



Latest developments in glass-based photonic circuits and assemblies

Adrien BILLAT – Business and Product Developer

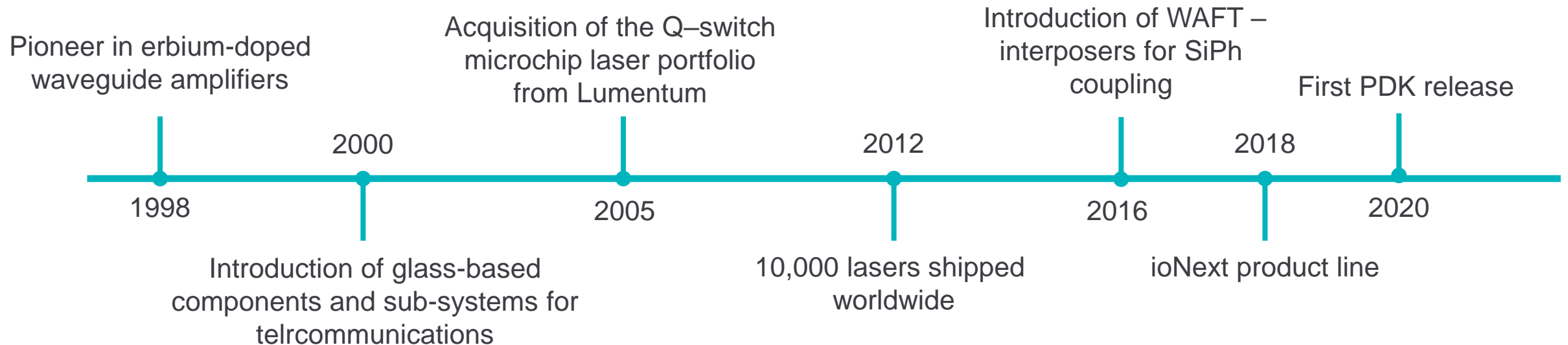
October 5th, 2021

Teem Photonics – Corporate background



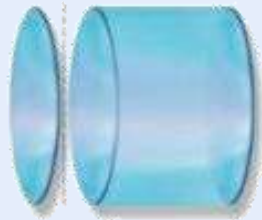
Established in 1998

- › Spin-off from Schneider Electric
- › Enters the telecommunication market for FTTH application
- › Strong R&D team, several patents

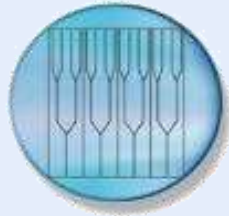


ioNext: a unique process on glass

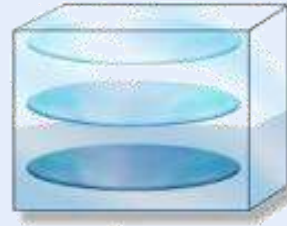
ioNext Process flow



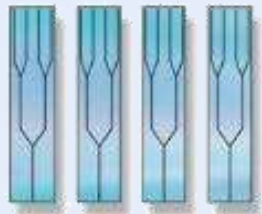
Wafer Preparation



Photolithography



Ion Exchange



Dicing

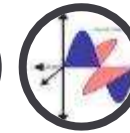
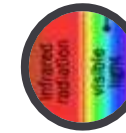


Pigtailing



Packaging

Value proposal



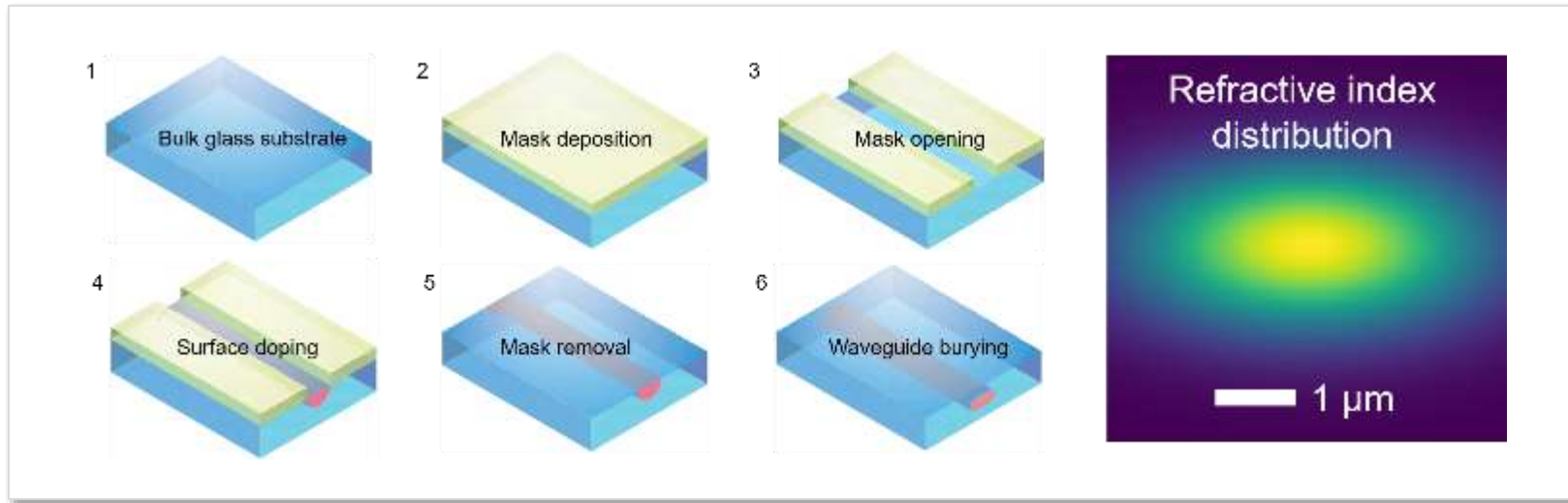
> Glass technology

- Large transparency band: 400 – 2000 nm
- Low propagation loss: 0.15 dB/cm
- Polarization maintaining
- Low PDL, low birefringence
- Low temperature dependence: $10^{-5} \Delta n_{\text{eff}}/K$

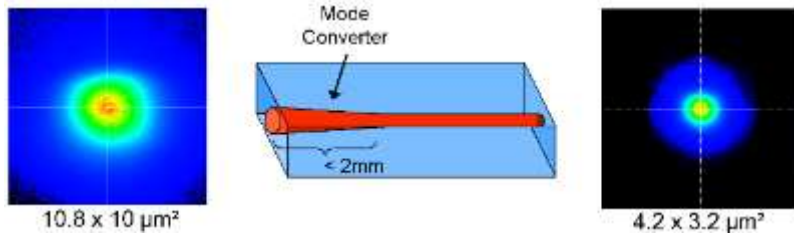
> ioNext specific

- Low fiber coupling loss : < 0.2dB
- Compactness : radius of curvature 800 μ m
- **Short turnaround time: down to 4 weeks**

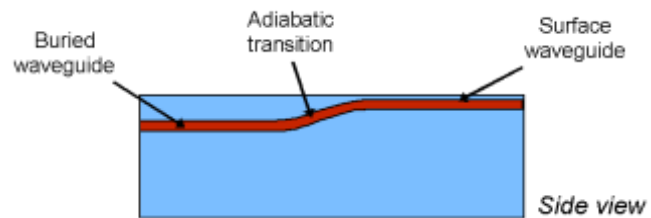
ioNext: the physics behind



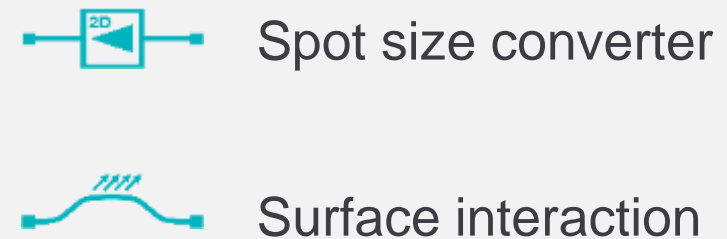
Spot size converter



Depth modulation



Extended optical library



ioNext: a complete photonic platform

 Splitters and couplers 

 Spot size converters

 MUX (duplexers and AWGs)

 Interferometers

 Waveguide crossings

 Waveguide Bragg gratings

 Thermo-optic phase shifter

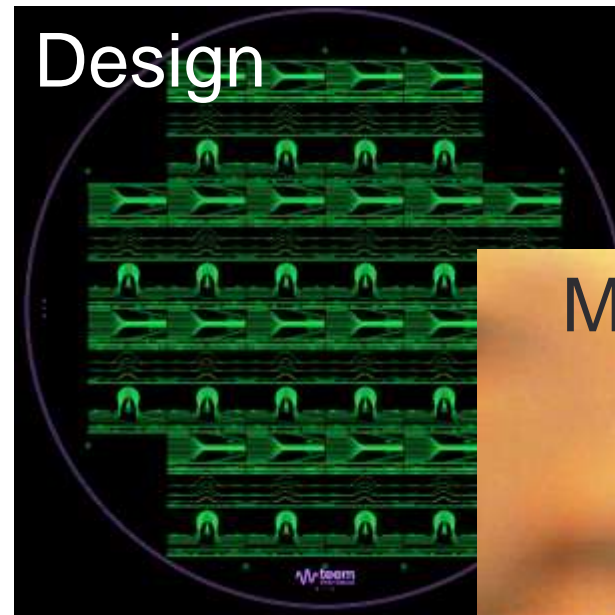
 Polarization filters

Coming soon

PDK available!

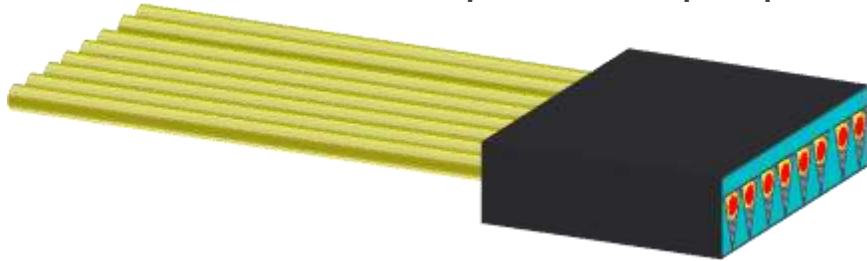


Nazca design
photonic IC design framework

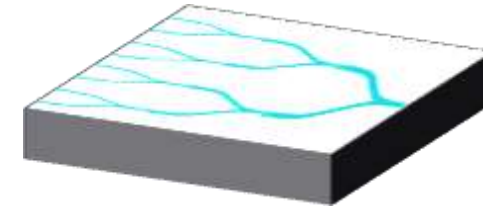


Fiber to chip assembly services

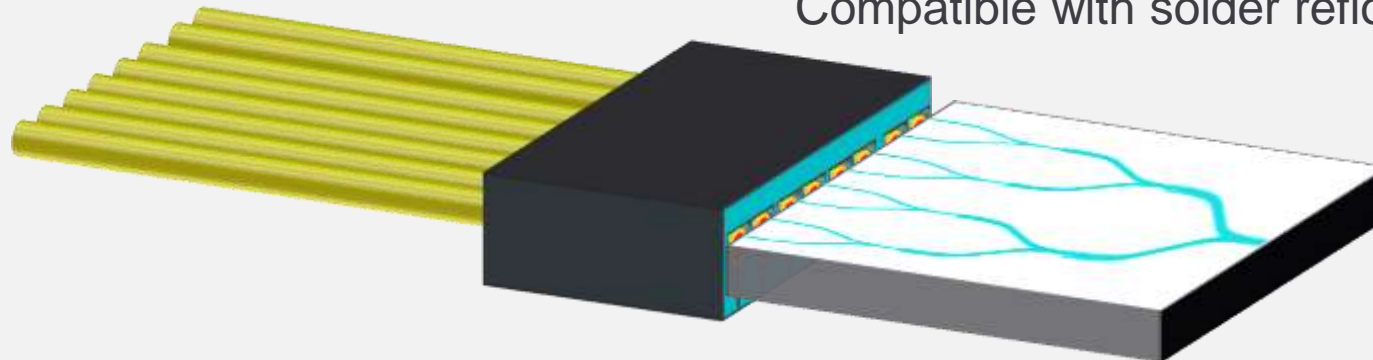
Fiber Array (FA)
SMF or PM fiber
250 μ m or 127 μ m pitch



ioNext chip
Polarization maintaining waveguides
250 μ m or 127 μ m pitch

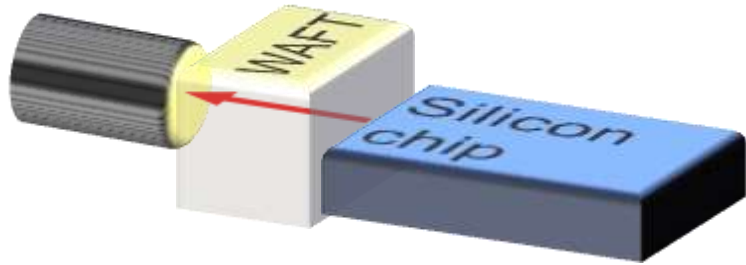


Fiber to chip assembly
Up to 64 fibers per FA
Insertion loss uniformity <0.2dB
Compatible with solder reflow



WAFT: PIC coupling solutions

Edge coupling

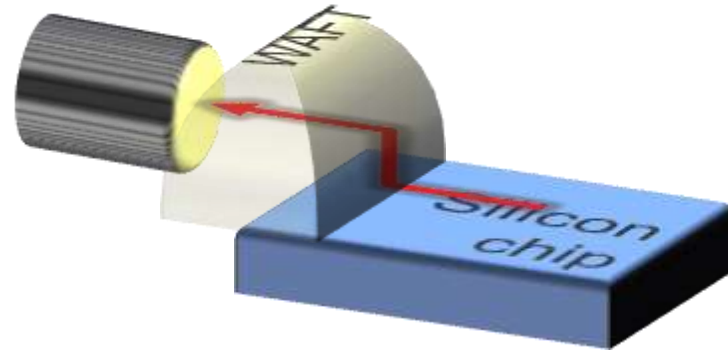


Low loss
WDM compatible
TE and TM compatible



Wafer-level incompatible
Tight alignment accuracy

Top coupling

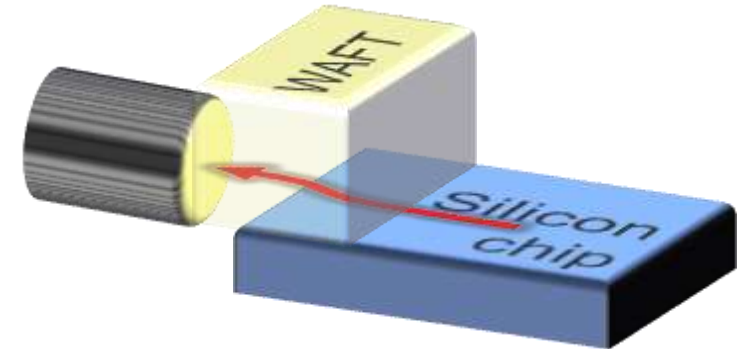


Alignment tolerant
Wafer level compatible



Grating coupler loss
WDM-limited
TM limited

Evanescent coupling



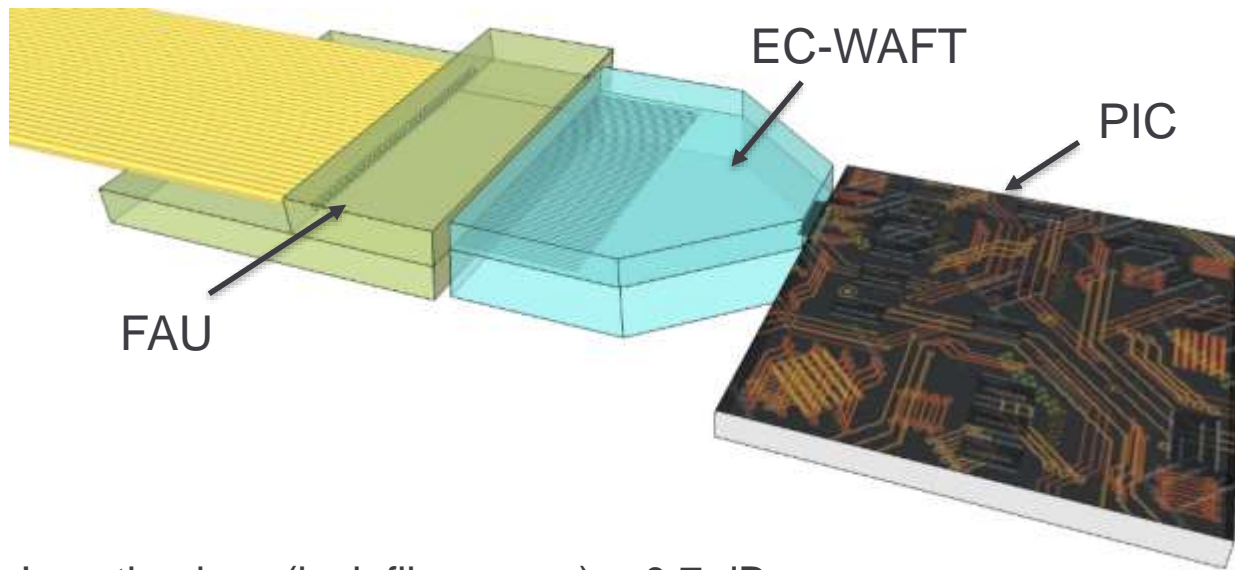
Low loss
WDM compatible
TE and TM compatible
Alignment tolerant



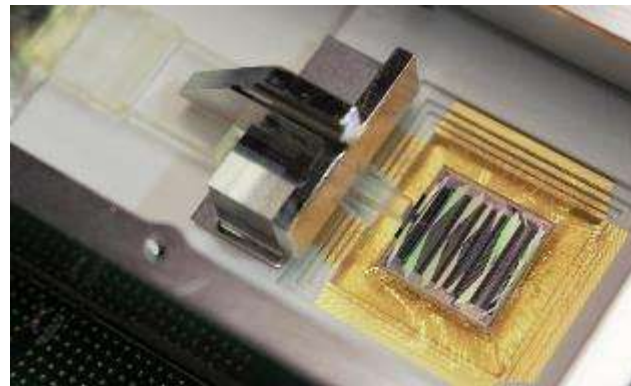
BEOL constraint

EC-WAFT : Pitch and mode adpatation

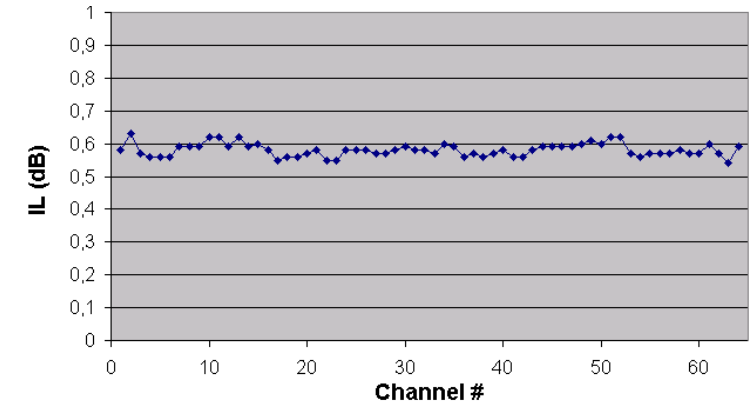
MFD matching to PIC edge couplers



Insertion loss (incl. fiber-array) < 0.7 dB
 PIC side MFD $4 \times 3 \mu\text{m}$ ($1/e^2$)
 PIC-side pitch > $20 \mu\text{m}$
 SM and PM fiber-compatible

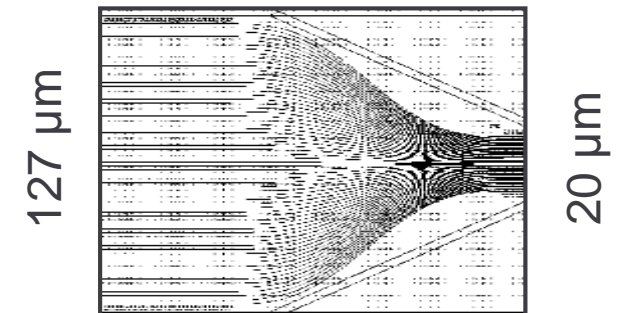


High channel count uniformity



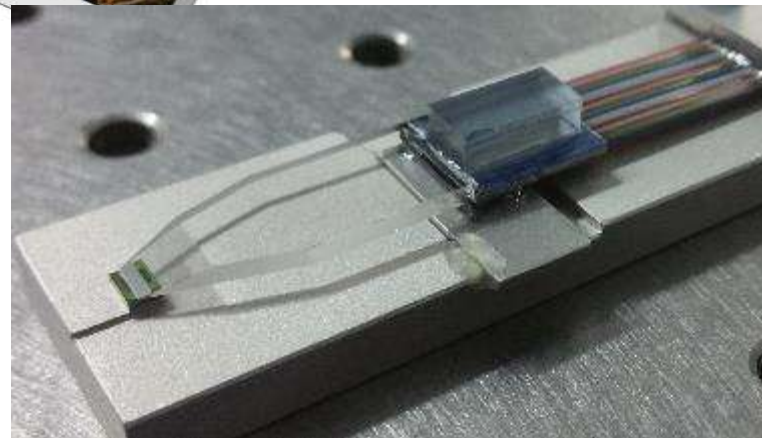
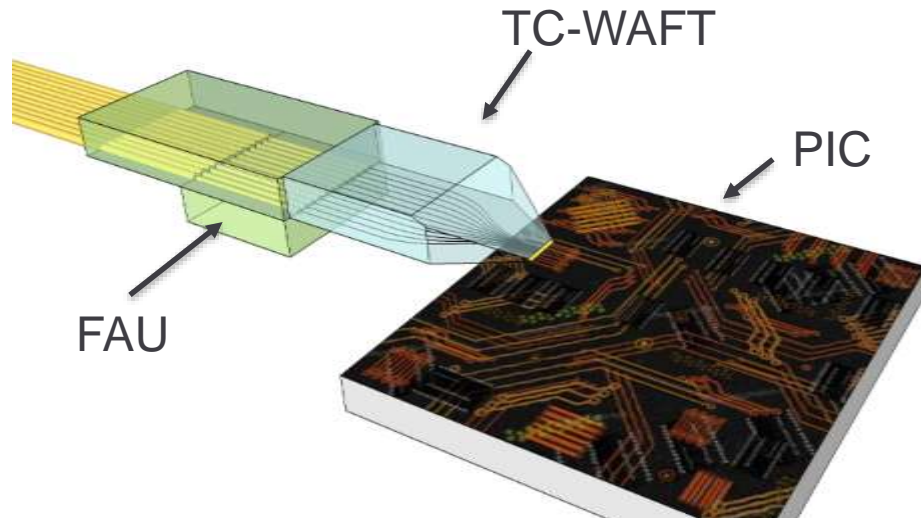
Large pitch adaptation

64 channels

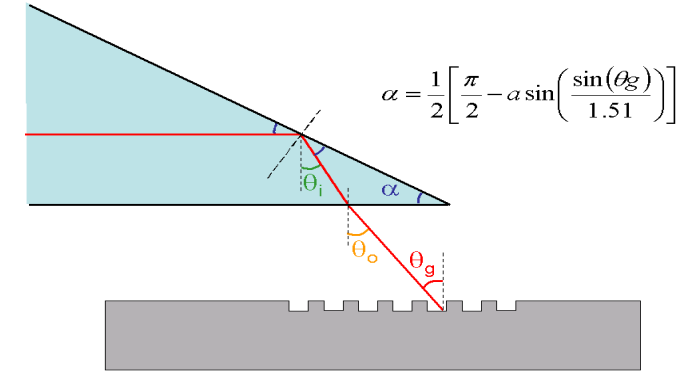


TC-WAFT series for SiP top coupling

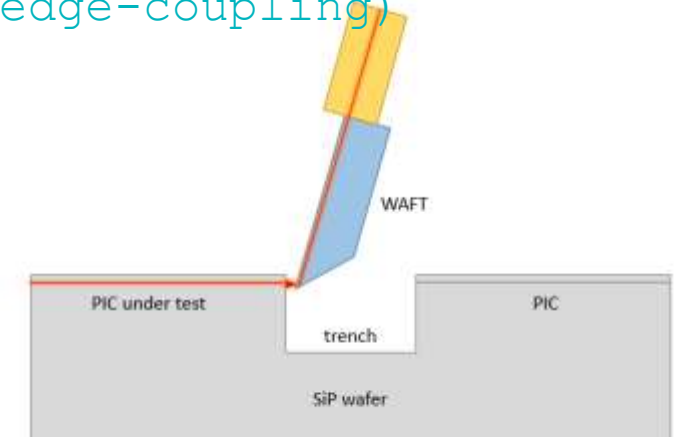
Low profile solution for grating couplers



- Packaging



- Wafer-level PIC testing (edge-coupling)



EV-WAFT series for evanescent coupling

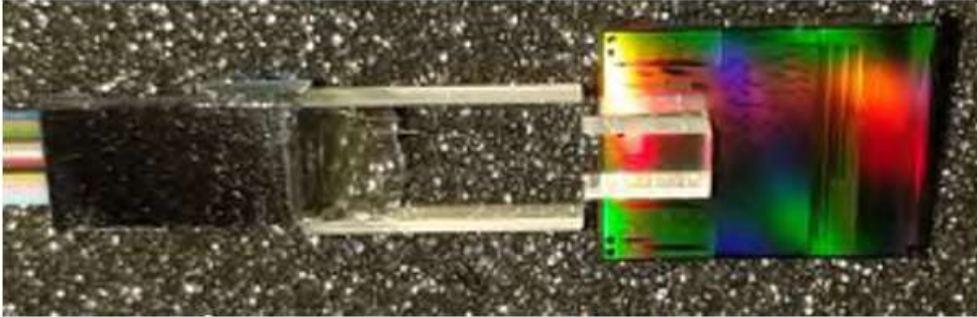


Fig 15 Glass interposer assembled Silicon Photonics Device with Cavity Etched BEOL

- Evanescent coupling to SiN-on-Si waveguide layer:**
- **Broadband and single-mode** in O-band and C-band
 - **Low loss** (< 1.5 dB from fiber to SiN)
 - **Low PDL** (< 0.2 dB)
 - **Alignment tolerant**

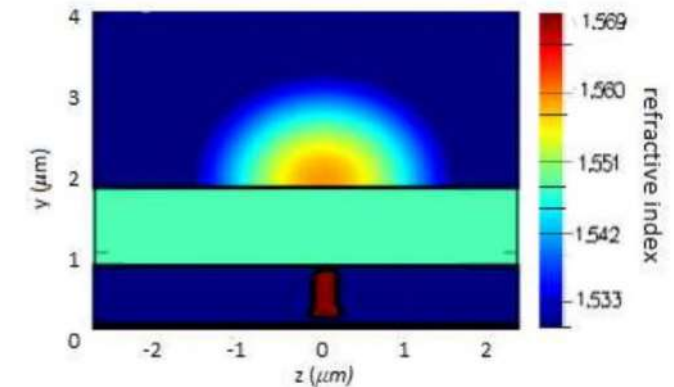
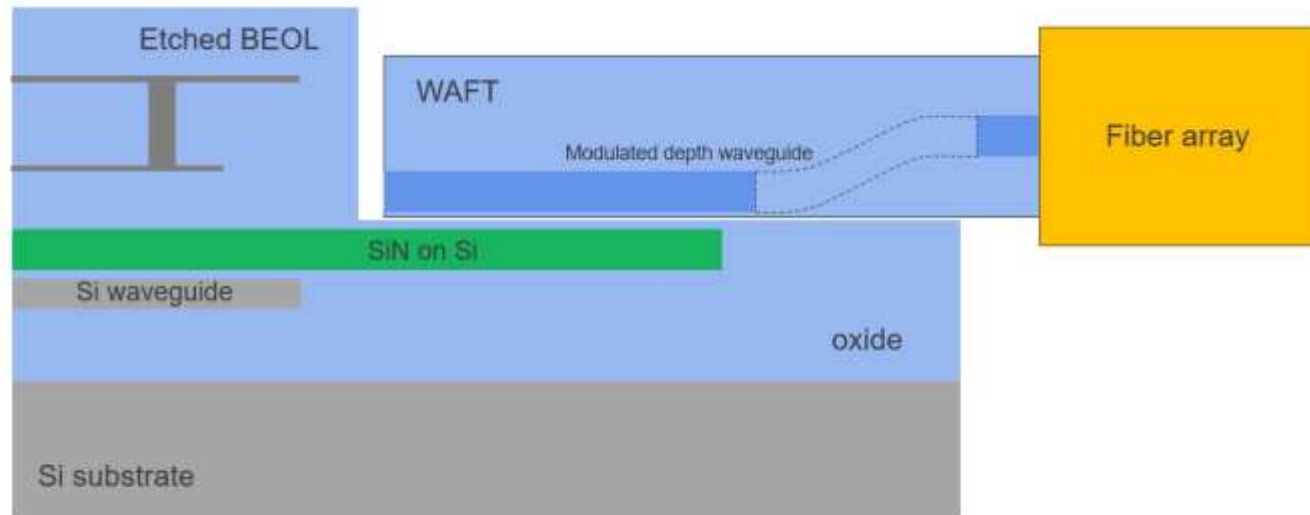
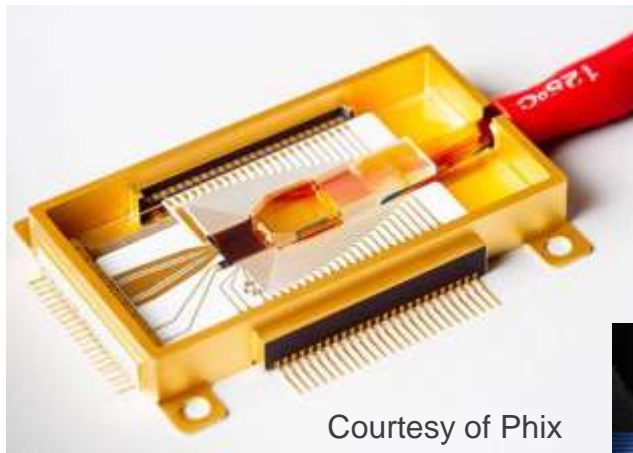


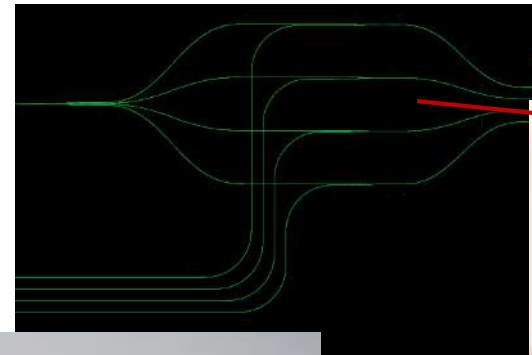
Fig. 11 Refractive index profile of the transversal cross-section of an Ion-Exchange interposer with mask width $1.7\mu\text{m}$, on top of the glue layer (light green) and the SiN waveguide (red)

Hybrid photonics concepts

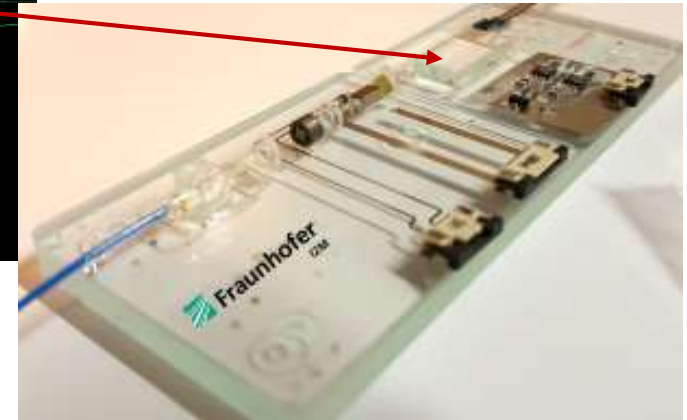
- AWGs can be combined with SiP (or LNOI) modulation through WAFT interposers
 - Temperature-robust
 - Fabrication tolerant
- Power per I/O can be reduced thanks to splitting WAFTs in LIDAR or photonic computing hardware
 - No undesired non-linear effect (free carrier absorption, spectral broadening...)
 - Higher damage threshold
- Glass hybridizes well with bulk LiNbO for complex modulation schemes



Courtesy of Phix



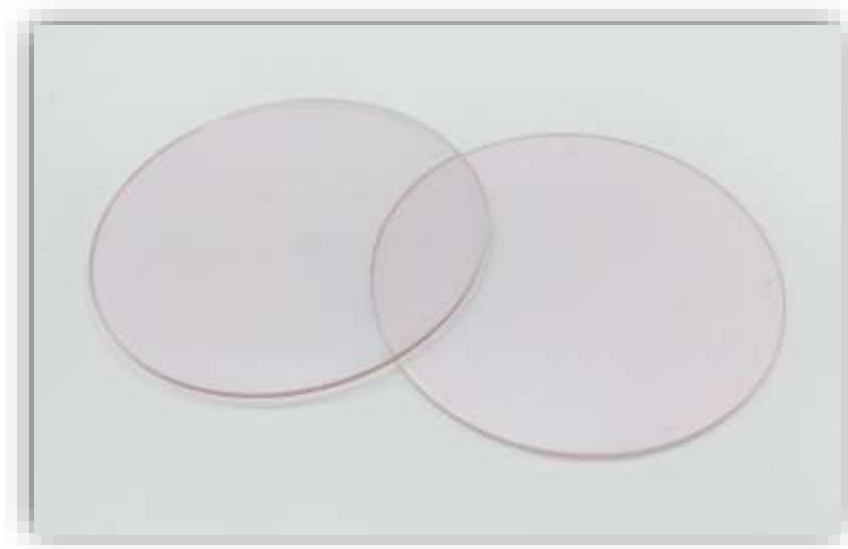
Courtesy of IPAG



Er:ioNext overview

Based on a proprietary glass:

- Er- and Er/Yb-doped
- Tailored for ioNext waveguides:
 - ✓ Low loss @ 1550nm
 - ✓ High confinement, short bends
 - ✓ Long gain sections (up to 50cm)
- High absorption @ 980nm
- Other rare-earth dopants possible (Nd, Yb, Pr...)



Applications:

- DFB laser arrays
- Amplifier arrays
- Amplifying WAFT/interposers for SiPh
- Customer-inspired ideas welcome!

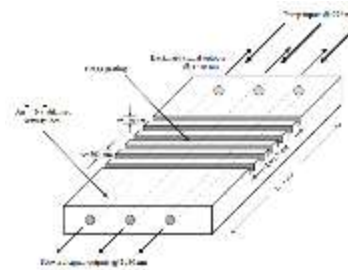
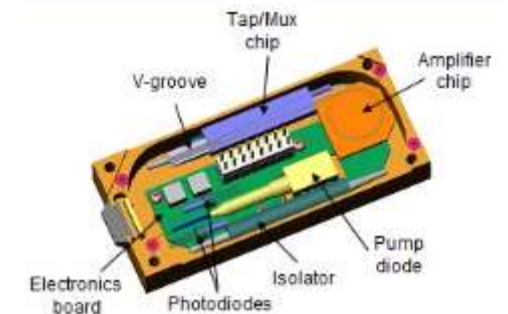
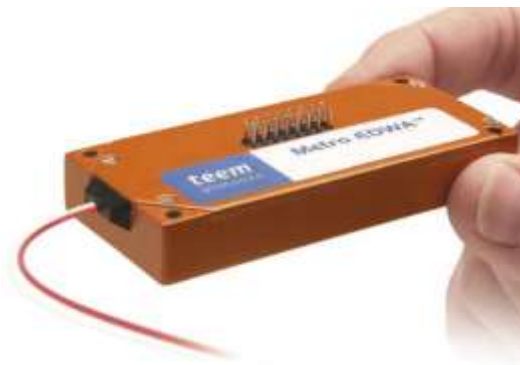


Figure 1: Schematic view of a laser chip



Thank you for your attention

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